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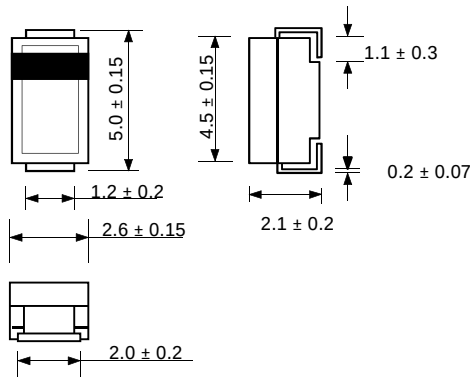
GN16

SURFACE MOUNT HIGH VOLTAGE RECTIFIER

PRV :1600 Volts
Io : 1.0 Ampere

SMA (DO-214AC)



Dimensions in millimeters

FEATURES :

* Glass passivated junction chip
* High current capability
* High surge current capability
* High reliability
* Low reverse current
* Low forward voltage drop
* Pb / RoHS Free

MECHANICAL DATA :

* Case : SMA Molded plastic
* Epoxy : UL94V-0 rate flame retardant
* Lead : Lead Formed for Surface Mount
* Polarity : Color band denotes cathode end
* Mounting position : Any
* Weight : 0.067 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

RATING	SYMBOL	VALUE	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	1600	V
Maximum RMS Voltage	V_{RMS}	1130	V
Maximum DC Blocking Voltage	V_{DC}	1600	V
Maximum Average Forward Current Ta = 50 °C	$I_{F(AV)}$	1.0	A
Maximum Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	30	A
Maximum Peak Forward Voltage at I_F = 1.0 A	V_F	1.25	V
Maximum DC Reverse Current Ta = 25 °C	I_R	5.0	µA
at Rated DC Blocking Voltage Ta = 100 °C	$I_{R(H)}$	100	µA
Typical Reverse Recovery Time (Note 1)	Trr	2.0	µs
Operating Junction Temperature Range	T_J	- 65 to + 175	°C
Storage Temperature Range	T_{STG}	- 65 to + 175	°C

Note : (1) Reverse Recovery Test Conditions : I_F = 0.5 A, I_R = 1.0 A, Irr = 0.25 A.

RATING AND CHARACTERISTIC CURVES (GN16)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

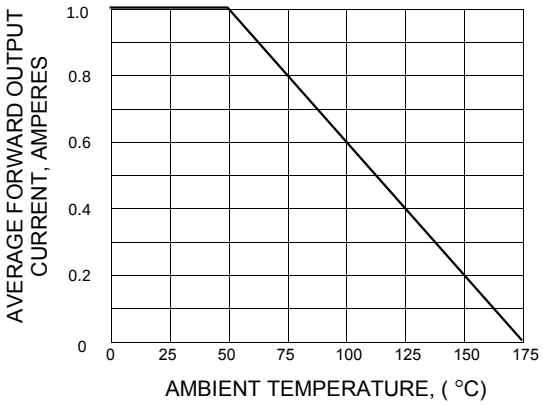


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

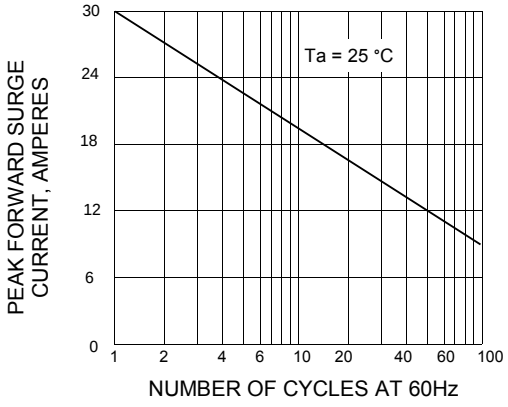


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

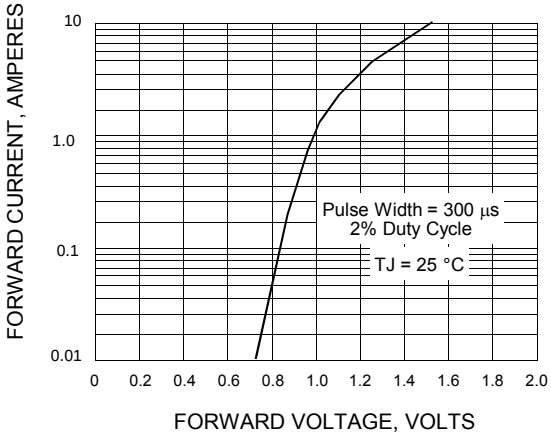


FIG.4 - TYPICAL REVERSE CHARACTERISTICS